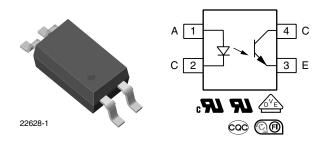


Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current, SSOP-4, Half Pitch, Mini-Flat Package



DESCRIPTION

The VOS617B series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES

- · High CTR with low input current
- · SSOP low profile package (half pitch)
- High collector emitter voltage, V_{CEO} = 80 V
- Isolation test voltage = 3750 V_{RMS}
- · Low coupling capacitance
- · High common mode transient immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT
HALOGEN
FREE
GREEN

APPLICATIONS

- Telecom
- Industrial controls
- · Battery powered equipment
- · Office machines
- · Programmable controllers

AGENCY APPROVALS

Safety application model number covering all products in this datasheet is VOS617B. This model number should be used when consulting safety agency documents.

- UL1577, file no. E76222, double protection
- cUL, accordance to CSA component acceptance service no. 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

ORDERING INFORM	IATION						
V O S 6 1 7 B - # X O O 1 T PART NUMBER CTR PACKAGE OPTION TAPE AND REEL SSOP-4							
AGENCY	AGENCY CTR (%)						
CERTIFIED/PACKAGE				5 mA			
UL, cUL, FIMKO, CQC	50 to 600	63 to 125	100 to 200	160 to 320	80 to 160	130 to 260	200 to 400
SSOP-4, 50 mil pitch	-	VOS617B-2T	VOS617B-3T	VOS617B-4T	VOS617B-7T	-	VOS617B-9T
UL, CUL, FIMKO, CQC, VDE (option 1)	50 to 600	63 to 125	100 to 200	160 to 320	80 to 160	130 to 260	200 to 400
SSOP-4, 50 mil pitch	VOS617B- X001T	VOS617B- 2X001T	VOS617B- 3X001T	VOS617B- 4X001T	VOS617B- 7X001T	VOS617B- 8X001T	VOS617B- 9X001T

Note

Additional options may be possible, please contact sales office.

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Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V _R	6	V				
Power dissipation		P _{diss}	100	mW				
Forward current		I _F	60	mA				
Surge forward current	t _p ≤ 10 μs	I _{FSM}	1.5	Α				
Junction temperature		Tj	125	°C				
OUTPUT								
Collector emitter voltage		V _{CEO}	80	V				
Emitter collector voltage		V _{ECO}	7	V				
Collector current		Ic	50	mA				
Power dissipation		P _{diss}	150	mW				
Junction temperature		Tj	125	°C				
COUPLER								
Total power dissipation		P _{tot}	250	mW				
Storage temperature range		T _{stg}	-55 to +150	°C				
Ambient temperature range		T _{amb}	-55 to +110	°C				
Soldering temperature (1)	t = 10 s	T _{sld}	260	°C				

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

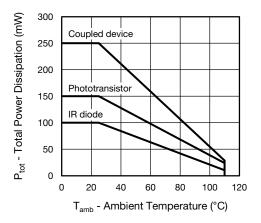


Fig. 1 - Power Dissipation vs. Ambient Temperature

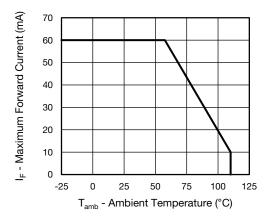


Fig. 2 - Maximum Forward Current vs. Ambient Temperature

Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 5 mA	V_{F}	-	1.18	1.5	V
Reverse current	V _R = 6 V	I _R	ı	0.01	10	μA
Capacitance	$V_R = 0 V, f = 1 MHz$	Cı	-	7.3	-	pF
OUTPUT						
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}	ı	0.3	100	nA
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	80	ı	-	V
Emitter collector breakdown voltage	I _E = 10 μA	BV _{ECO}	7	-	-	V
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}	-	5	-	pF
COUPLER						
Collector emitter saturation voltage	$I_F = 5 \text{ mA}, I_C = 2.5 \text{ mA}$	V _{CEsat}	-	0.25	0.4	V
Cut-off frequency	$I_F = 10$ mA, $V_{CC} = 5$ V, $R_L = 100$ Ω	f _{ctr}	-	155	-	kHz

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	I _F = 5 mA, V _{CE} = 5 V	VOS617B	CTR	50	-	600	%
		VOS617B-2	CTR	63	-	125	%
		VOS617B-3	CTR	100	-	200	%
		VOS617B-4	CTR	160	-	320	%
		VOS617B-7	CTR	80	-	160	%
		VOS617B-8	CTR	130	=	260	%
		VOS617B-9	CTR	200	=	400	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
NON-SATURATED								
Rise and fall time		t _r	-	3	-	μs		
Fall time	$I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V},$	t _f	-	3	-	μs		
Turn-on time	$R_L = 100 \Omega$	t _{on}	-	6	-	μs		
Turn-off time		t _{off}	-	4	-	μs		
SATURATED								
Rise and fall time	I_F = 1.6 mA, V_{CC} = 5 V, R_L = 1.9 kΩ	t _r	-	3	-	μs		
Fall time		t _f	-	12	-	μs		
Turn-on time		t _{on}	-	4	-	μs		
Turn-off time		t _{off}	-	18	-	μs		

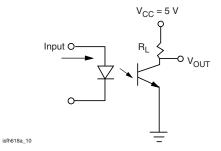


Fig. 3 - Test Circuit

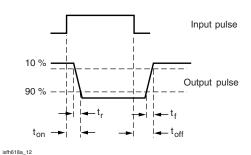


Fig. 4 - Test Circuit and Waveforms



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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification (according to IEC 68 part 1)			55/110/21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	40 % to 60 % RH, AC test of 1 min	V _{ISO}	3750	V _{RMS}
Maximum transient isolation voltage		V _{IOTM}	6000	V
Maximum repetitive peak isolation voltage		V_{IORM}	707	V
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹	Ω
Isolation resistance (under fault conditions)	$V_{IO} = 500 \text{ V}, T_{amb} = T_{SI}$	R _{IO}	10 ⁹	Ω
Output safety power		P_{SO}	350	mW
Input safety current		I _{SI}	200	mA
Input safety temperature		T _{SI}	175	°C
Apparent charge test voltage (method A)	V_{IORM} x 1.6 = V_{PR} , type and sample test t_m = 60 s, partial discharge < 5 pC	V_{PR}	1132	V _{peak}
Apparent charge test voltage (method B)	V_{IORM} x 1.875 = V_{PR} , 100 % production test with t_m = 1 s, partial discharge < 5 pC	V_{PR}	1326	V _{peak}
Creepage distance			≥ 5	mm
Clearance distance			≥ 5	mm
Insulation thickness		DTI	≥ 0.4	mm
Environment (pollution degree in accordance to DI	N VDE 0109)		2	

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

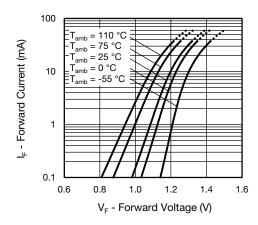


Fig. 5 - Forward Voltage vs. Forward Current

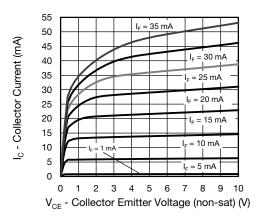
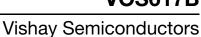


Fig. 6 - Collector Current vs. Collector Emitter Voltage

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.





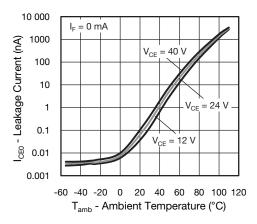


Fig. 7 - Leakage Current vs. Ambient Temperature

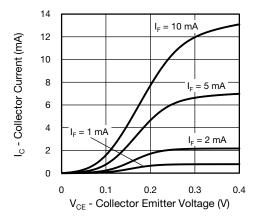


Fig. 8 - Collector Current vs. Collector Emitter Voltage

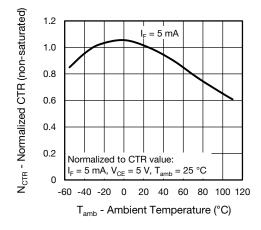


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

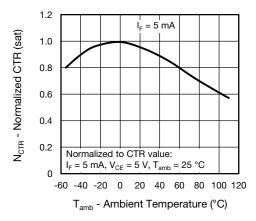


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

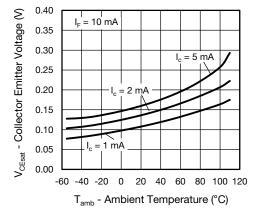


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

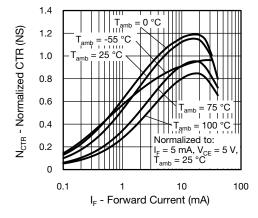
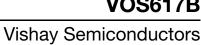


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current





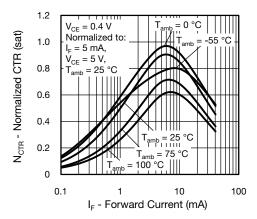


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

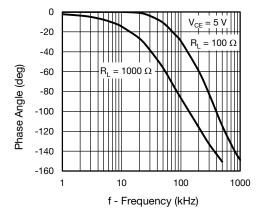


Fig. 14 - F_{CTR} vs. Phase Angle

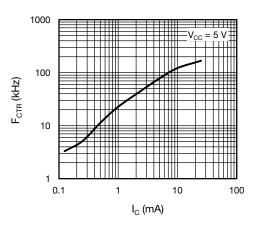


Fig. 15 - F_{CTR} vs. Collector Current

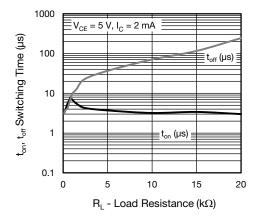
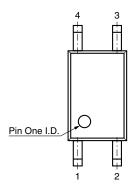


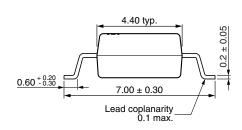
Fig. 16 - Switching Time vs. Load Resistance

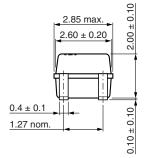


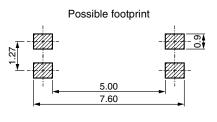
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PACKAGE DIMENSIONS (in millimeters)

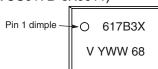








PACKAGE MARKING (example of VOS617B-3X001T)



Notes

- Option 1 is reflected with letter "X".
- Tape and reel suffix (T) is not part of the package marking.



PACKAGING INFORMATION (TAPE AND REEL) (in millimeters)

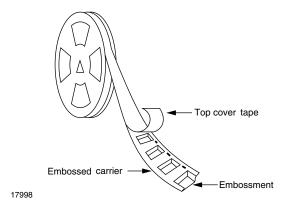


Fig. 17 - Tape and Reel Shipping Medium

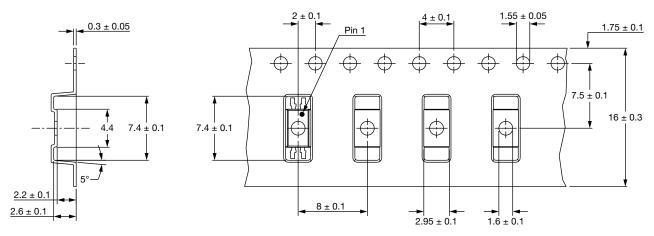


Fig. 18 - Tape and Reel Packing (3000 parts per reel)

SOLDER PROFILES

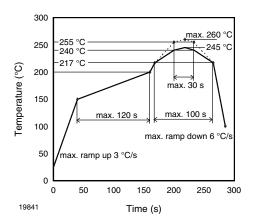


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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Revision: 02-Oct-12 Document Number: 91000